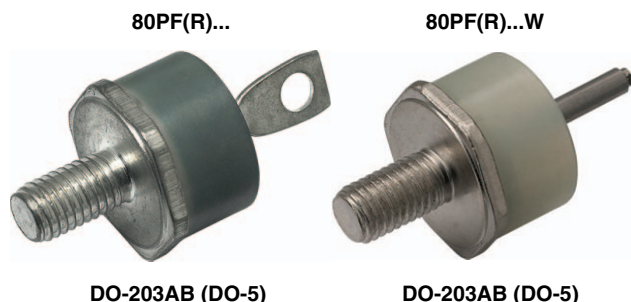


## Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 80 A



DO-203AB (DO-5)

DO-203AB (DO-5)

### FEATURES

- High surge current capability
- Designed for a wide range of applications
- Stud cathode and stud anode version
- Wire version available
- Low thermal resistance
- Designed and qualified for multiple level
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


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COMPLIANT

### TYPICAL APPLICATIONS

- Battery charges
- Converters
- Power supplies
- Machine tool controls
- Welding

### PRODUCT SUMMARY

|                       |                 |
|-----------------------|-----------------|
| $I_{F(AV)}$           | 80 A            |
| Package               | DO-203AB (DO-5) |
| Circuit configuration | Single diode    |

### MAJOR RATINGS AND CHARACTERISTICS

| PARAMETER    | TEST CONDITIONS | VALUES       | UNITS            |
|--------------|-----------------|--------------|------------------|
| $I_{F(AV)}$  |                 | 80           | A                |
|              | $T_C$           | 123          | °C               |
| $I_{F(RMS)}$ |                 | 126          | A                |
| $I_{FSM}$    | 50 Hz           | 1200         | A                |
|              | 60 Hz           | 1250         |                  |
| $I^2t$       | 50 Hz           | 7100         | A <sup>2</sup> s |
|              | 60 Hz           | 6450         |                  |
| $V_{RRM}$    | Range           | 1400 to 1600 | V                |
| $T_J$        |                 | -55 to 150   | °C               |

### ELECTRICAL SPECIFICATIONS

#### VOLTAGE RATINGS

| TYPE NUMBER      | VOLTAGE CODE | $V_{RRM}$ , MAXIMUM REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | $V_{RSM}$ , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | $I_{RRM}$ MAXIMUM<br>AT $T_J = 150\text{ °C}$<br>mA |
|------------------|--------------|-------------------------------------------------------------|-----------------------------------------------------------------|-----------------------------------------------------|
| VS-80PF(R)...(W) | 140          | 1400                                                        | 1650                                                            | 4.5                                                 |
|                  | 160          | 1600                                                        | 1900                                                            |                                                     |



| FORWARD CONDUCTION                                            |                     |                                                                                                          |                                  |                                                       |        |                   |                  |
|---------------------------------------------------------------|---------------------|----------------------------------------------------------------------------------------------------------|----------------------------------|-------------------------------------------------------|--------|-------------------|------------------|
| PARAMETER                                                     | SYMBOL              | TEST CONDITIONS                                                                                          |                                  |                                                       | VALUES | UNITS             |                  |
| Maximum average forward current at case temperature           | I <sub>F(AV)</sub>  | 180° conduction, half sine wave                                                                          |                                  |                                                       | 80     | A                 |                  |
|                                                               |                     |                                                                                                          |                                  |                                                       | 123    | °C                |                  |
| Maximum RMS forward current                                   | I <sub>F(RMS)</sub> |                                                                                                          |                                  |                                                       | 126    | A                 |                  |
| Maximum peak, one-cycle forward, non-repetitive surge current | I <sub>FSM</sub>    | t = 10 ms                                                                                                | No voltage reapplied             | Sinusoidal half wave, initial T <sub>J</sub> = 150 °C | 1200   | A                 |                  |
|                                                               |                     | t = 8.3 ms                                                                                               |                                  |                                                       | 1250   |                   |                  |
|                                                               |                     | t = 10 ms                                                                                                | 100 % V <sub>RRM</sub> reapplied |                                                       | 1000   |                   |                  |
|                                                               |                     | t = 8.3 ms                                                                                               |                                  |                                                       | 1050   |                   |                  |
| Maximum I <sup>2</sup> t for fusing                           | I <sup>2</sup> t    | t = 10 ms                                                                                                | No voltage reapplied             |                                                       |        | 7100              | A <sup>2</sup> s |
|                                                               |                     | t = 8.3 ms                                                                                               |                                  |                                                       |        | 6450              |                  |
|                                                               |                     | t = 10 ms                                                                                                | 100 % V <sub>RRM</sub> reapplied |                                                       |        | 5000              |                  |
|                                                               |                     | t = 8.3 ms                                                                                               |                                  |                                                       |        | 4550              |                  |
| Maximum I <sup>2</sup> √t for fusing                          | I <sup>2</sup> √t   | t = 0.1 ms to 10 ms, no voltage reapplied                                                                |                                  |                                                       | 71 000 | A <sup>2</sup> √s |                  |
| Low level value of threshold voltage                          | V <sub>F(TO)</sub>  | (16.7 % × π × I <sub>F(AV)</sub> < I < π × I <sub>F(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum |                                  |                                                       | 0.73   | V                 |                  |
| Low level value of forward slope resistance                   | r <sub>f</sub>      | (16.7 % × π × I <sub>F(AV)</sub> < I < π × I <sub>F(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum |                                  |                                                       | 3.0    | mΩ                |                  |
| Maximum forward voltage drop                                  | V <sub>FM</sub>     | I <sub>pk</sub> = 220 A, T <sub>J</sub> = 25 °C, t <sub>p</sub> = 400 μs rectangular wave                |                                  |                                                       | 1.46   | V                 |                  |

| THERMAL AND MECHANICAL SPECIFICATIONS                    |                |                                                              |                 |                     |
|----------------------------------------------------------|----------------|--------------------------------------------------------------|-----------------|---------------------|
| PARAMETER                                                | SYMBOL         | TEST CONDITIONS                                              | VALUES          | UNITS               |
| Maximum junction operating and storage temperature range | $T_J, T_{Stg}$ |                                                              | -55 to 180      | °C                  |
| Maximum thermal resistance, junction to case             | $R_{thJC}$     | DC operation                                                 | 0.30            | K/W                 |
| Maximum thermal resistance, case to heatsink             | $R_{thCS}$     | Mounting surface, smooth, flat and greased                   | 0.25            |                     |
| Allowable mounting torque                                |                | Not lubricated threads, tightening on nut <sup>(1)</sup>     | 3.4<br>(30)     | N · m<br>(lbf · in) |
|                                                          |                | Lubricated threads, tightening on nut <sup>(1)</sup>         | 2.3<br>(20)     |                     |
|                                                          |                | Not lubricated threads, tightening on Hexagon <sup>(2)</sup> | 4.2<br>(37)     |                     |
|                                                          |                | Lubricated threads, tightening on Hexagon <sup>(2)</sup>     | 3.2<br>(28)     |                     |
| Approximate weight                                       |                |                                                              | 15.8            | g                   |
|                                                          |                |                                                              | 0.56            | oz.                 |
| Case style                                               |                | See dimensions - link at the end of datasheet                | DO-203AB (DO-5) |                     |

**Notes**

- (1) Recommended for pass-through holes  
 (2) Torque must be applicable only to Hexagon and not to plastic structure, recommended for holed heatsink

| $\Delta R_{thJC}$ CONDUCTION |                       |                        |                     |       |
|------------------------------|-----------------------|------------------------|---------------------|-------|
| CONDUCTION ANGLE             | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS     | UNITS |
| 180°                         | 0.14                  | 0.10                   | $T_J = T_J$ maximum | K/W   |
| 120°                         | 0.16                  | 0.17                   |                     |       |
| 90°                          | 0.21                  | 0.22                   |                     |       |
| 60°                          | 0.30                  | 0.31                   |                     |       |
| 30°                          | 0.50                  | 0.50                   |                     |       |

**Note**

- The table above shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC

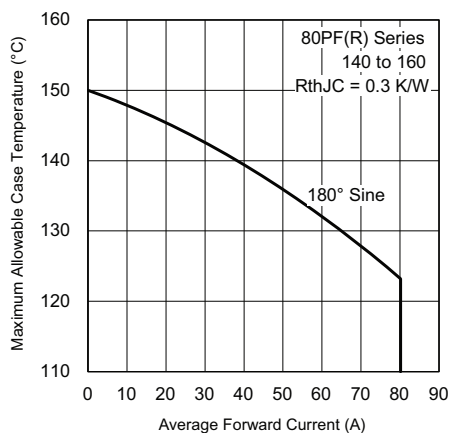


Fig. 1 - Current Ratings Characteristics

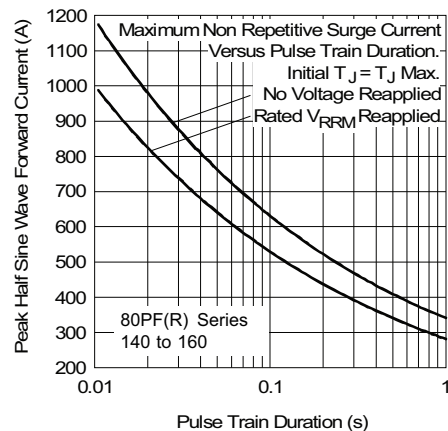


Fig. 3 - Forward Power Loss Characteristics

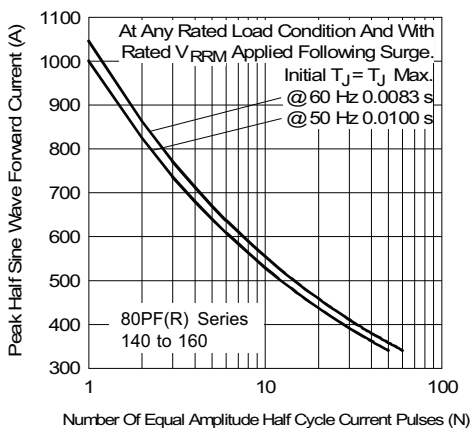


Fig. 2 - Current Ratings Characteristics

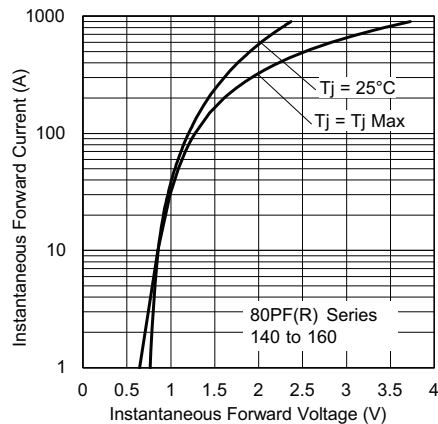


Fig. 4 - Forward Power Loss Characteristics

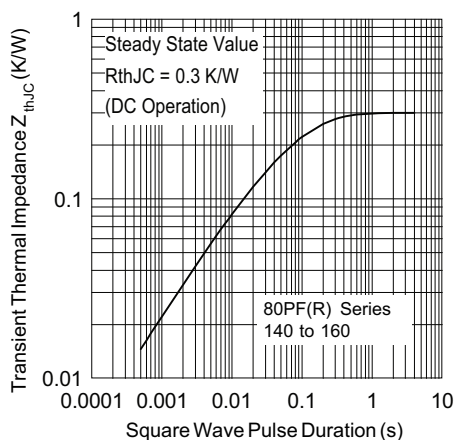


Fig. 5 - Maximum Non-Repetitive Surge Current



## ORDERING INFORMATION TABLE

|             |     |    |    |   |     |   |
|-------------|-----|----|----|---|-----|---|
| Device code | VS- | 80 | PF | R | 160 | W |
|             | 1   | 2  | 3  | 4 | 5   | 6 |

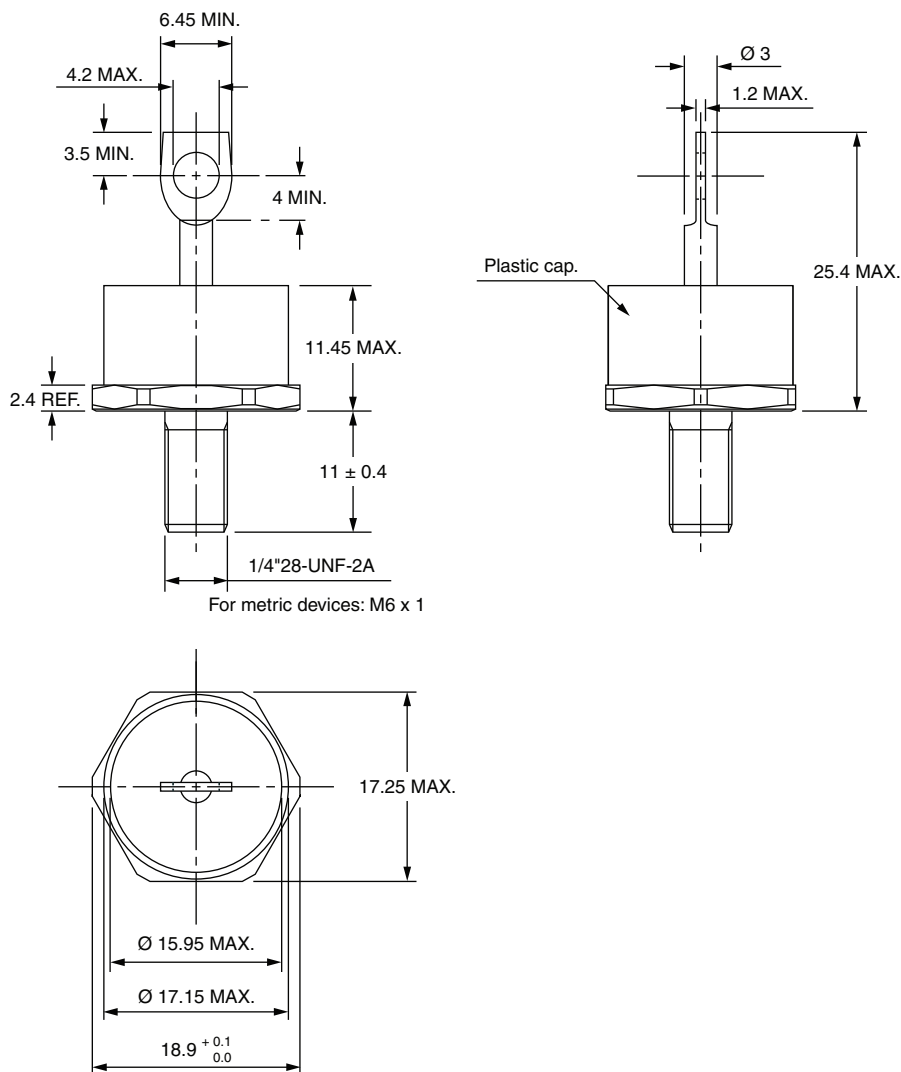
- |          |   |                                                                                                                                                                                                                                               |
|----------|---|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>1</b> | - | Vishay Semiconductors product                                                                                                                                                                                                                 |
| <b>2</b> | - | 80 = Standard device                                                                                                                                                                                                                          |
| <b>3</b> | - | PF = Plastic package                                                                                                                                                                                                                          |
| <b>4</b> | - | <ul style="list-style-type: none"><li>• None = Stud normal polarity (cathode to stud)</li><li>• R = Stud reverse polarity (anode to stud)</li></ul>                                                                                           |
| <b>5</b> | - | Voltage code x 10 = $V_{RRM}$ (see Voltage Ratings table)                                                                                                                                                                                     |
| <b>6</b> | - | <ul style="list-style-type: none"><li>• None = Standard terminal<br/>(see dimensions for 80PF(R)... - link at the end of datasheet)</li><li>• W = Wire terminal<br/>(see dimensions for 80PF(R)...W - link at the end of datasheet)</li></ul> |

| LINKS TO RELATED DOCUMENTS |                                                                        |
|----------------------------|------------------------------------------------------------------------|
| Dimensions                 | <a href="http://www.vishay.com/doc?95345">www.vishay.com/doc?95345</a> |



## DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

**DIMENSIONS FOR 80PF(R), 50PF(R) AND 95PF(R) SERIES** in millimeters

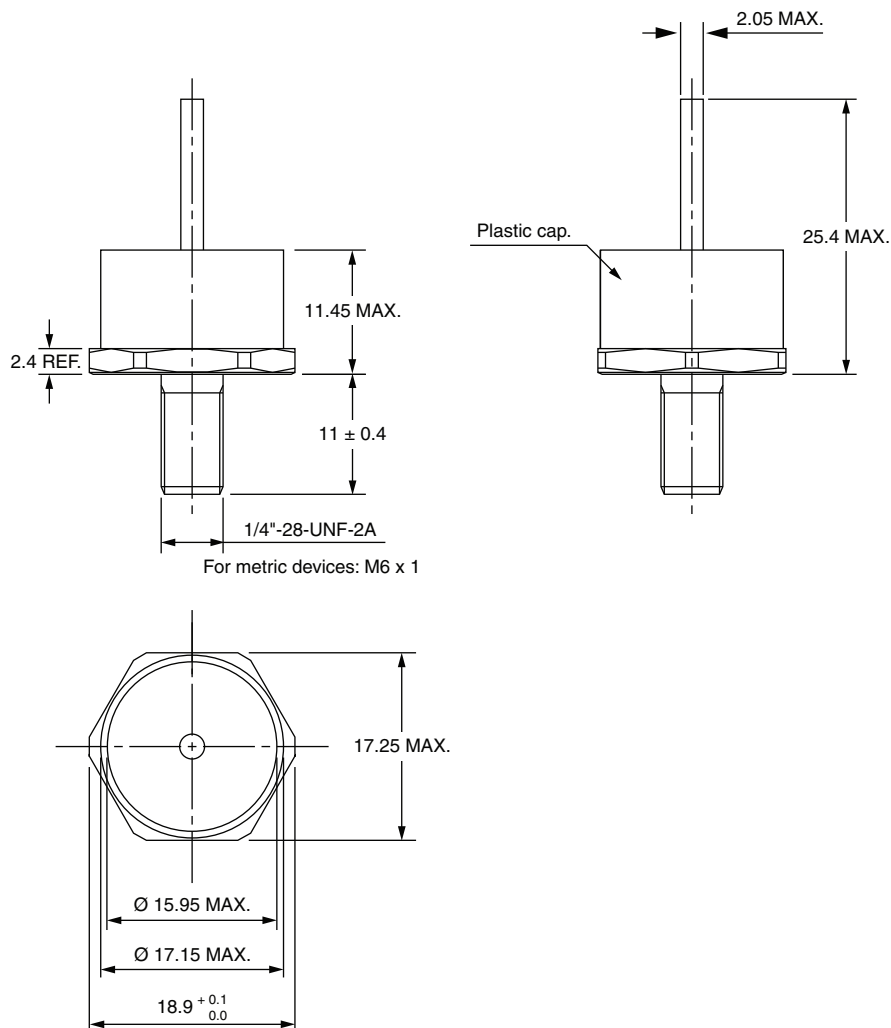


### Note

- For metric device please contact factory



## DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W) AND 95PF(R)...(W) SERIES in millimeters

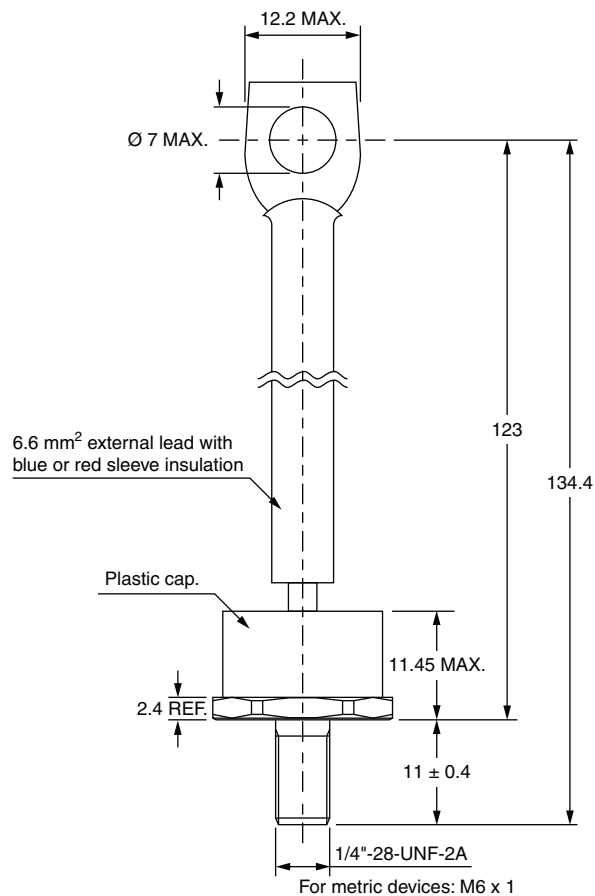


### Note

- For metric device please contact factory



## DIMENSIONS FOR 52PF(R), 82PF(R) AND 97PF(R) SERIES in millimeters



### Note

- For metric device please contact factory



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### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

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